

TECHNICAL DATA DATA SHEET 5159, REV. -

HERMETIC POWER MOSFET N-CHANNEL

FEATURES:

- 600 Volt, 60A, 55 milli-Ohm
- Isolated Hermetic Metal Package
- Very low Gate Charge
- Very Low R_{DS (on)}
- Low package inductance-easy to drive and protect

MAXIMUM RATINGS

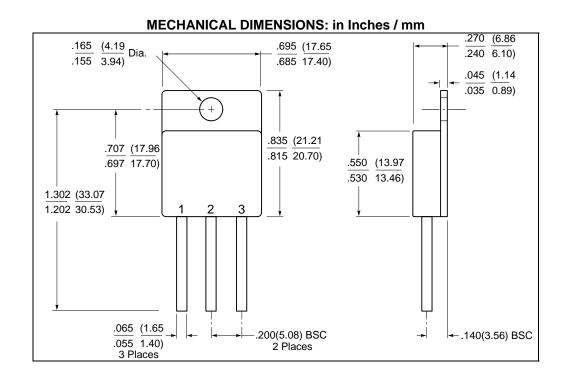
ALL RATINGS ARE AT T $_{\rm C}$ = 25 $^{\circ}{\rm C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	V_{GS}	-	-	±20	Volts
ON-STATE DRAIN CURRENT @ T _C = 25°C	I _{D (on)}	-	-	60	Amps
PULSED DRAIN CURRENT @ T _C = 25°C	I _{DM}	1	-	220	Amps
OPERATING AND STORAGE TEMPERATURE	T_{OP}/T_{STG}	-55	-	+150	°C
THERMAL RESISTANCE, JUNCTION TO CASE	R_{thJC}	-	-	0.36	°C/W
TOTAL DEVICE DISSIPATION @ T _C = 25°C	P _D	-	-	350	Watts

ELECTRICAL CHARACTERISTICS

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
DRAIN TO SOURCE BREAKDOWN VOLTAGE	BV _{DSS}	600	-	-	Volts
$V_{GS} = 0V, I_D = 250 \mu A$					
STATIC DRAIN TO SOURCE ON STATE RESISTANCE		-	-		
$V_{GS} = 10V, I_{D} = 44A$	R _{DS(ON)}			0.055	Ω
GATE THRESHOLD VOLTAGE $V_{DS} = V_{GS}$, $I_D = 3mA$	$V_{GS(th)}$	2.0	-	4.0	Volts
ZERO GATE VOLTAGE DRAIN CURRENT		-			
$V_{DS} = 600V, V_{GS} = 0V$	I _{DSS}		-	20	μΑ
$V_{DS} = 0.8$ xMax. Rating, $V_{GS} = 0$ V, $T_{J} = 125$ °C			-	500	μΑ
GATE TO SOURCE LEAKAGE FORWARD V _{GS} = 20V	I_{GSS}	-	-	100	nA
GATE TO SOURCE LEAKAGE REVERSE V _{GS} = -20V				-100	
TURN ON DELAY TIME $V_{DS} = 400V$,	$t_{d(ON)}$	-	40	-	
RISE TIME $I_D = 44A$,	t _r		30		nsec
TURN OFF DELAY TIME $R_G = 3.3\Omega$,	$t_{d(OFF)}$		130		
FALL TIME $V_{GS} = 10V$	t _f		20		
DIODE FORWARD VOLTAGE $I_S = 44A$,	V_{SD}	-	-	1.35	Volts
$V_{GS} = 0V$					
REVERSE RECOVERY TIME					
$I_F = 44A$, $-di/dt = 100A/\mu sec$, $V_R = 100V$	t _{rr}	-	600	-	nsec
INPUT CAPACITANCE $V_{GS} = 0 V$	C_{iss}	-	6800	-	
OUTPUT CAPACITANCE $V_{DS} = 100 \text{ V}$	C_{oss}		320		pF
f = 1 MHz					
GATE CHARGE					
$I_F = 44A$, $V_{DS} = 400 \text{ V}$, $V_{GS} = 10 \text{ V}$, $R_G = 3.3 \Omega$	Q_{gs}	-	34	-	_
	Q_{gd}		51	-	nC
	Q_g		150	190	

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TO-258

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET IN A	DRAIN	SOURCE	GATE
TO-258 PACKAGE			

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